NSN 5962-01-351-7279

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View Online at https://aerobasegroup.com/nsn/5962-01-351-7279

Overall Length:
0.540 inches
Overall Width:
Between 0.745 inches and 1.040 inches
Body Length:
0.540 inches
Body Width:
Between 0.245 inches and 0.300 inches
Body Height:
Between 0.045 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5895-01-299-3419 converter, signal data
Features Provided:
Bipolar and programmable and high impedance and w/clock and bidirectional and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Bipolar metal-oxide semiconductor
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
F-9 mil-m-38510
Current Rating Per Characteristic:
12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Solder
Product Name:
And-or invert gate array
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal	Type	Δnd	Quantity:	
ı C ı IIIIII aı	ı ype	Allu	Qualitity.	

20 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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